4 Line EMI Filter with ESD Protection

This device is a 4 line EMI filter array for wireless applications. Greater than -30 dB attenuation is obtained at frequencies from 800 MHz to 3.0 GHz. It also offers ESD protection clamping transients from static discharges. ESD protection is provided across all capacitors.

Features

- EMI Filtering and ESD Protection
- Integration of 28 Discrete Components
- DFN Package, 1.35 x 3.0 mm
- Moisture Sensitivity Level 1
- ESD Ratings: IEC61000-4-2 (Level 4) Machine Model = C

Human Body Model = 3B

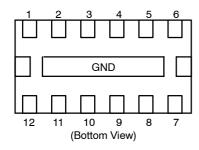
• This is a Pb-Free Device*

Benefits

- Reduces EMI/RFI Emissions on a Data Line
- Integrated Solution Offers Cost and Space Savings in a DFN Package
- Excellent S21 Characteristics with very Low Parasitic Inductances
- Integrated Solution Improves System Reliability
- Compatible Footprint to BGA or Flip-Chip Package

Applications

- EMI Filtering and ESD Protection for Data Lines
- Wireless Phones
- PDAs and Handheld Products
- Digital Camera
- LCD Displays

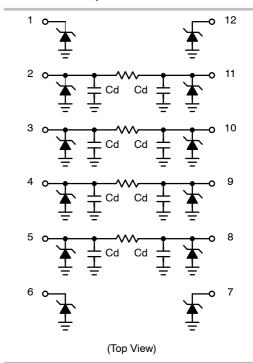


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MARKING DIAGRAM



DFN12 CASE 506AD



6402= Specific Device Code

 $\overline{M} = Month$

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NUF6402MNT1G	DFN12 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
ESD Discharge IEC61000-4-2 Contact Discharge	V_{PP}	8.0	kV
Operating Temperature Range	T _{OP}	-40 to 85	°C
Storage Temperature Range	T _{STG}	-55 to 150	°C
Maximum Lead Temperature for Soldering Purposes (1.8 in from case for 10 seconds)	T _L	260	°C

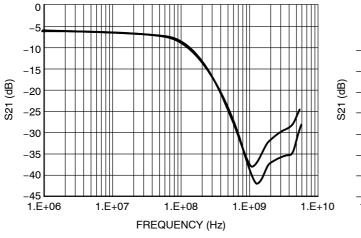
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Maximum Reverse Working Voltage	V _{RWM}				5.0	V
Breakdown Voltage	V_{BR}	I _R = 1.0 mA	6.0	7.0	8.0	V
Leakage Current	I _R	V _{RWM} = 3.0 V		0.1	1.0	μΑ
Resistance	R _A	I _R = 20 mA	85	100	115	Ω
Capacitance (Notes 1 and 2)	Cd	V _R = 2.5 V, f = 1.0 MHz		17	20	pF
Cut-Off Frequency (Note 3)	f _{3dB}	Above this frequency, appreciable attenuation occurs		95		MHz

Measured at 25°C, V_R = 2.5 V, f = 1.0 MHz.
 Total line capacitance is 2 times the Diode Capacitance (Cd).

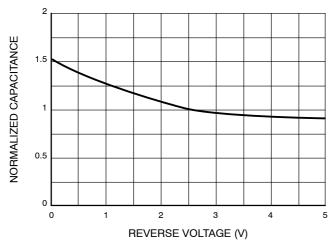
^{3.} 50Ω source and 50Ω load termination.



0 -5 -10 -15 -20 -25 -30 -35 -40 -45 1.E+06 1.E+07 1.E+08 1.E+09 1.E+10 FREQUENCY (Hz)

Figure 4. Insertion Loss Characteristic

Figure 1. Analog Crosstalk Curve



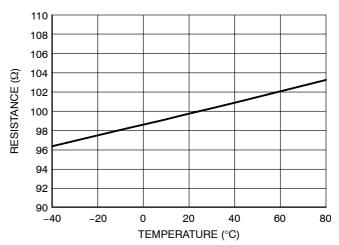
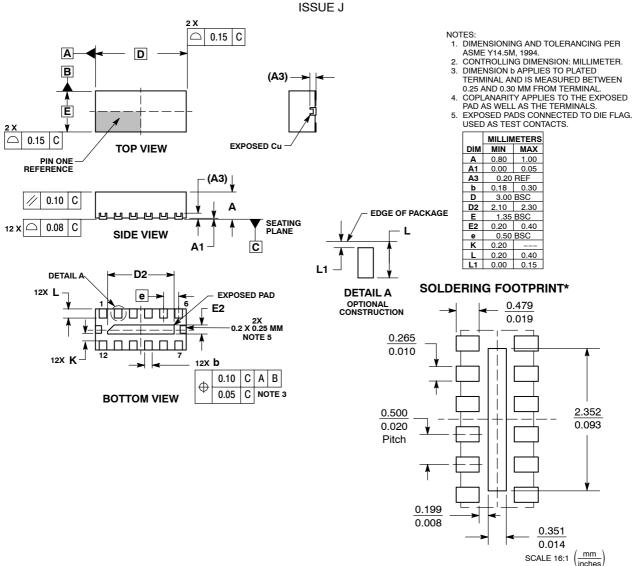


Figure 2. Typical Capacitance vs.
Reverse Biased Voltage
(Normalized Capacitance, Cd @ 2.5 V)

Figure 3. Typical Resistance over Temperature

PACKAGE DIMENSIONS

DFN12 3.0x1.35, 0.5PCASE 506AD-01



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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